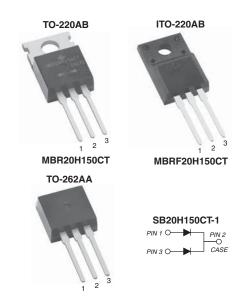


Vishay General Semiconductor

RoHS

## **Dual Common Cathode High Voltage Schottky Rectifier**

Low Leakage Current 5.0 µA



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 2 x 10 A					
V <sub>RRM</sub>	150 V				
I <sub>FSM</sub>	200 A				
V <sub>F</sub>	0.75 V				
T <sub>J</sub> max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-262AA				
Diode variations	Dual Common Cathode				

#### **FEATURES**

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- · Low forward voltage drop
- High frequency operation
- Solder dip 275 °C max., 10 s per JESD 22-B106
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>



For use in high frequency inverters, freewheeling, and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR20H150CT	MBRF20H150CT	SB20H150CT-1	UNIT
Maximum repetitive peak reverse voltage		$V_{RRM}$	150			V
Working peak reverse voltage		$V_{RWM}$		150		V
Maximum DC blocking voltage		$V_{DC}$		150		V
Maximum average ferward rectified current	per device	,	20			Α
Maximum average forward rectified current	per diode	I <sub>F(AV)</sub>	10			
Peak forward surge current 8.3 ms single half superimposed on rated load per diode	f sine-wave	I <sub>FSM</sub>	200			Α
Peak repetitive reverse current per diode at t <sub>p</sub> = 2 µs, 1 kHz		I <sub>RRM</sub>	1.0			Α
Peak non-repetitive reverse surge energy per (8/20 µs waveform)	diode	E <sub>RSM</sub>	10			mJ
Non-repetitive avalanche energy per diode at $I_{AS} = 1.5 \text{ A}$ , $L = 10 \text{ mH}$	25 °C,	E <sub>AS</sub>	11.25			mJ
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000			V/µs
Operating junction and storage temperature r	ange	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175			°C
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min		V <sub>AC</sub>	1500		V	



Vishay General Semiconductor

_			
W	ww.v	/ishay	y.com

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
	I <sub>F</sub> = 10 A T <sub>C</sub> = 25 °C		0.90			
Maximum instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C	V <sub>F</sub> <sup>(1)</sup>	0.75	V	
	I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C		0.99		
	I <sub>F</sub> = 20 A	T <sub>C</sub> = 125 °C		0.86		
Maximum reverse current per diode		T <sub>J</sub> = 25 °C	I <sub>R</sub> <sup>(1)</sup>	5.0	μΑ	
at working peak reverse voltage		T <sub>J</sub> = 125 °C		1.0	mA	

#### **Notes**

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.2	4.2	2.2	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20H150CT-E3/45	2.06	45	50/tube	Tube		
ITO-220AB	MBRF20H150CT-E3/45	2.20	45	50/tube	Tube		
TO-262AA	SB20H150CT-1E3/45	1.58	45	50/tube	Tube		

#### Note

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

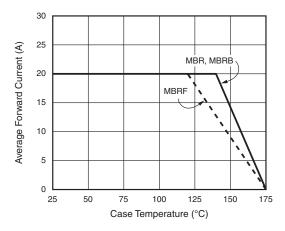


Fig. 1 - Forward Derating Curve (Total)

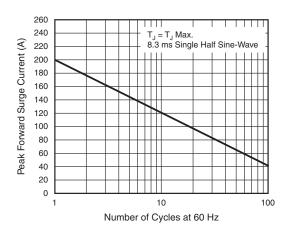


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

<sup>(1)</sup> AEC-Q101 qualified



## Vishay General Semiconductor

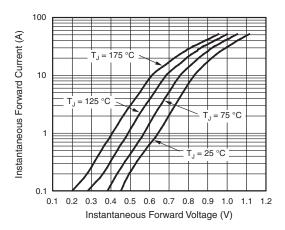


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

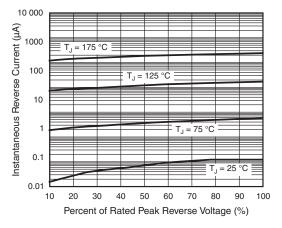


Fig. 4 - Typical Reverse Characteristics Per Diode

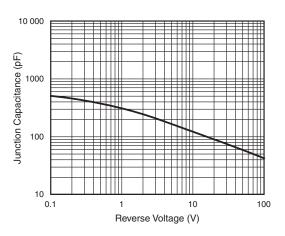


Fig. 5 - Typical Junction Capacitance Per Diode

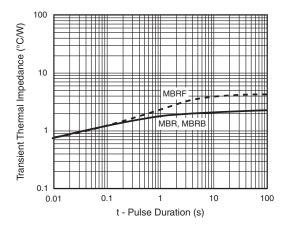
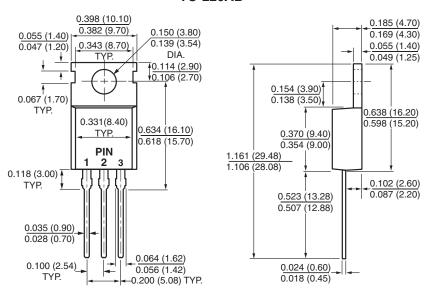


Fig. 6 - Typical Transient Thermal Impedance Per Diode

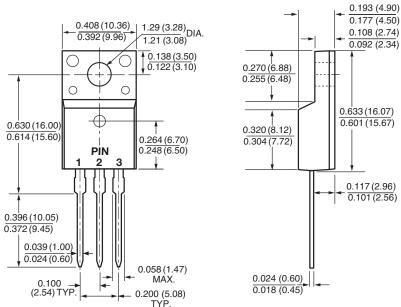
Vishay General Semiconductor

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

#### **TO-220AB**



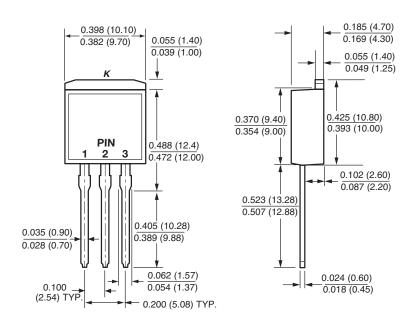
### ITO-220AB





Vishay General Semiconductor

#### **TO-262AA**





## **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 13-Jun-16 1 Document Number: 91000

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

## Vishay:

MBR20H150CT/45 MBR20H150CT-E3/45 MBRF20H150CT/45 MBRF20H150CT-E3/45